

Supporting Information

Optimized Structure of Silane-core Containing Host Materials for Highly Efficient Blue Thermally Activated Delayed Fluorescence Organic Light Emitting Diodes

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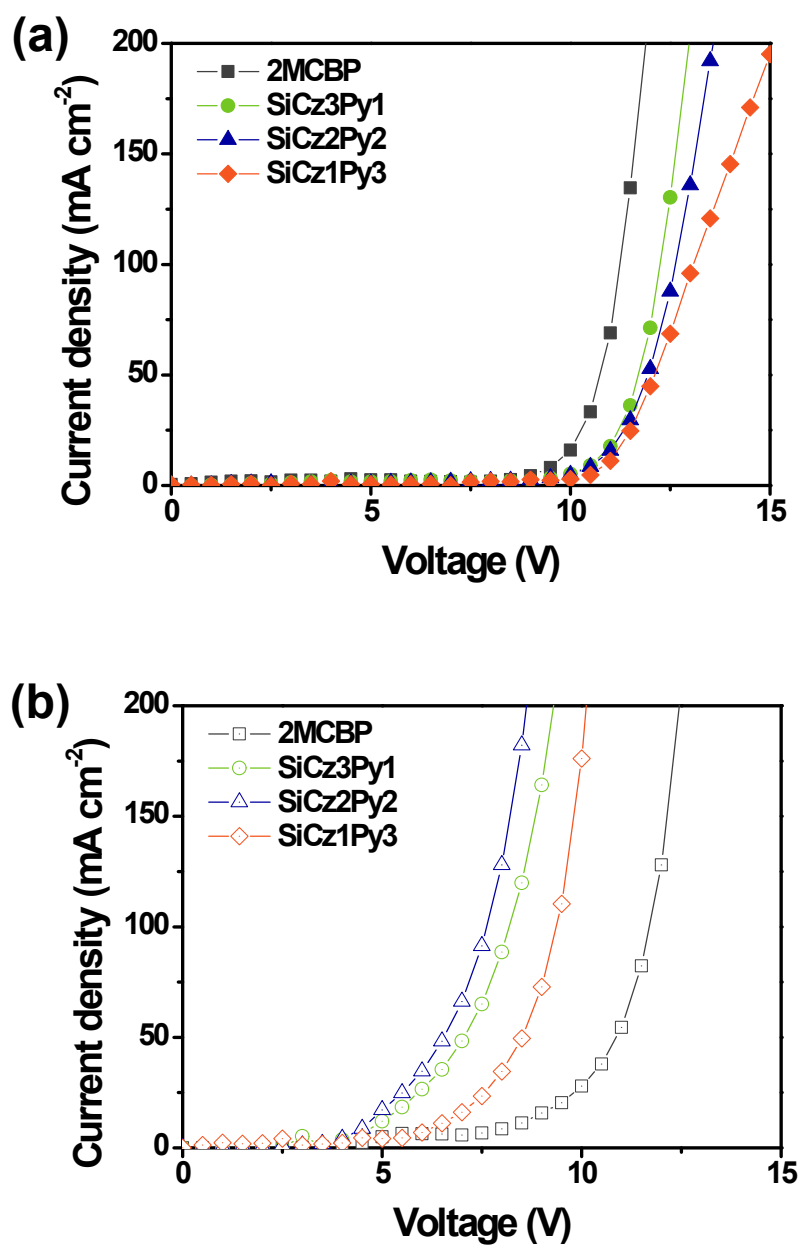


Figure S1. Current density-voltage (J - V) characteristics of (a) hole-only devices (HODs) and (b) electron-only devices (EODs).